500 mA, Very Low Dropout Bias Rail CMOS Voltage Regulator

The NCP145 is a 500 mA VLDO equipped with NMOS pass transistor and a separate bias supply voltage (V_{BIAS}). The device provides very stable, accurate output voltage with low noise suitable for space constrained, noise sensitive applications. In order to optimize performance for battery operated portable applications, the NCP145 features low I_Q consumption. The XDFN4 1.2 mm x 1.2 mm package is optimized for use in space constrained applications.

Features

- Input Voltage Range: 1.0 V to 5.5 V
 Bias Voltage Range: 2.4 V to 5.5 V
 Fixed Voltage Versions Available
- Output Voltage Range: 1.0 V to 1.8 V (Fixed)
- ±1.5% Accuracy over Temperature, 0.5% V_{OUT} @ 25°C
- Ultra-Low Dropout: Typ. 140 mV at 500 mA
- Very Low Bias Input Current of Typ. 80 μA
- Very Low Bias Input Current in Disable Mode: Typ. 0.5 μA
- Logic Level Enable Input for ON/OFF Control
- Output Active Discharge Option Available
- Stable with a 2.2 μF Ceramic Capacitor
- Available in XDFN4 1.2 mm x 1.2 mm x 0.4 mm Package
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Battery-powered Equipment
- Smartphones, Tablets
- Cameras, DVRs, STB and Camcorders

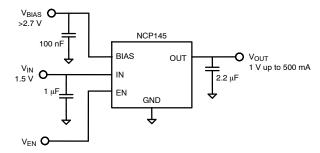


Figure 1. Typical Application Schematics



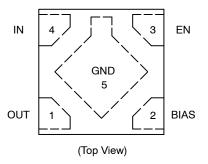
ON Semiconductor™

www.onsemi.com



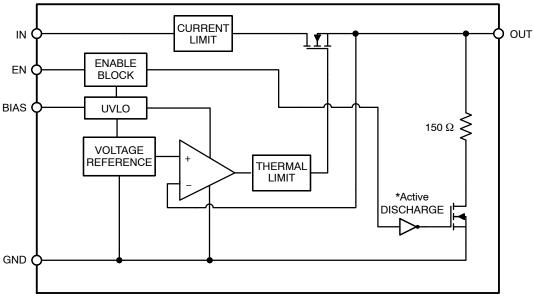
XX = Specific Device Code M = Date Code

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 9 of this data sheet.



^{*}Active output discharge function is present only in NCP145AMXyyyTCG devices. yyy denotes the particular output voltage option.

Figure 2. Simplified Schematic Block Diagram

PIN FUNCTION DESCRIPTION

Pin No. XDFN4	Pin Name	Description
1	OUT	Regulated Output Voltage pin
2	BIAS	Bias voltage supply for internal control circuits. This pin is monitored by internal Under-Voltage Lockout Circuit.
3	EN	Enable pin. Driving this pin high enables the regulator. Driving this pin low puts the regulator into shutdown mode.
4	IN	Input Voltage Supply pin
5	GND	Ground

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage (Note 1)	V _{IN}	-0.3 to 6	V
Output Voltage	V _{OUT}	-0.3 to $(V_{IN}+0.3) \le 6$	V
Chip Enable, Bias Input	V _{EN} , V _{BIAS}	-0.3 to 6	V
Output Short Circuit Duration	t _{SC}	unlimited	s
Maximum Junction Temperature	T _J	150	°C
Storage Temperature	T _{STG}	-55 to 150	°C
ESD Capability, Human Body Model (Note 2)	ESD _{HBM}	2000	V
ESD Capability, Machine Model (Note 2)	ESD _{MM}	200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

2. This device series incorporates ESD protection (except OUT pin) and is tested by the following methods:

ESD Human Body Model tested per EIA/JESD22-A115

- - ESD Machine Model tested per EIA/JESD22-A115
 - Latchup Current Maximum Rating tested per JEDEC standard: JESD78.

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics, XDFN4 1.2 mm x 1.2 mm Thermal Resistance, Junction-to-Air (Note 3)	$R_{ hetaJA}$	170	°C/W

This data was derived by thermal simulations for a single device mounted on the 40 mm x 40 mm x 1.6 mm FR4 PCB with 2-ounce 800 sq mm copper area on top and bottom.

ELECTRICAL CHARACTERISTICS $-40^{\circ}C \le T_J \le 85^{\circ}C$; $V_{BIAS} = 2.7 \text{ V or } (V_{OUT} + 1.6 \text{ V})$, whichever is greater, $V_{IN} = V_{OUT(NOM)} + 0.3 \text{ V}$, $I_{OUT} = 1 \text{ mA}$, $V_{EN} = 1 \text{ V}$, unless otherwise noted. $I_{EN} = 1 \text{ M}$, $I_{EN} = 1 \text{ V}$, unless otherwise noted. (Note 4)

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
Operating Input Voltage Range		V _{IN}	V _{OUT} + V _{DO}		5.5	V
Operating Bias Voltage Range		V _{BIAS}	(V _{OUT} + 1.40) ≥ 2.4		5.5	V
Undervoltage Lock-out V _{BIAS} Rising Hysteresis		UVLO		1.6 0.2		V
Output Voltage Accuracy		V _{OUT}		±0.5		%
Output Voltage Accuracy	$ \begin{array}{l} -40^{\circ}C \leq T_{J} \leq 85^{\circ}C, \ V_{OUT(NOM)} + 0.3 \ V \leq V_{IN} \leq \\ V_{OUT(NOM)} + 1.0 \ V, \ 2.7 \ V \ or \ (V_{OUT(NOM)} + \\ 1.6 \ V), \ whichever \ is \ greater < V_{BIAS} < 5.5 \ V, \\ 1 \ mA < I_{OUT} < 500 \ mA \end{array} $	V _{OUT}	-1.5		+1.5	%
V _{IN} Line Regulation	$V_{OUT(NOM)} + 0.3 \text{ V} \le V_{IN} \le 5.0 \text{ V}$	Line _{Reg}		0.01		%/V
V _{BIAS} Line Regulation	2.7 V or ($V_{OUT(NOM)}$ + 1.6 V), whichever is greater < V_{BIAS} < 5.5 V	Line _{Reg}		0.01		%/V
Load Regulation	I _{OUT} = 1 mA to 500 mA	Load _{Reg}		1.5		mV
V _{IN} Dropout Voltage	I _{OUT} = 150 mA (Note 5)	V _{DO}		37	75	mV
	I _{OUT} = 500 mA (Note 5)	V _{DO}		140	250]
V _{BIAS} Dropout Voltage	I _{OUT} = 500 mA, V _{IN} = V _{BIAS} (Note 5)	V_{DO}		1.1	1.5	V
Output Current Limit V _{OUT} = 90% V _{OUT(NOM)}		I _{CL}	550	800	1000	mA
Bias Pin Operating Current	V _{BIAS} = 2.7 V	I _{BIAS}		80	110	μΑ
Bias Pin Disable Current	V _{EN} ≤ 0.4 V	I _{BIAS(DIS)}		0.5	1	μΑ
Vinput Pin Disable Current	V _{EN} ≤ 0.4 V	I _{VIN(DIS)}		0.5	1	μΑ
EN Pin Threshold Voltage	EN Input Voltage "H"	V _{EN(H)}	0.9			V
	EN Input Voltage "L"	V _{EN(L)}			0.4	
EN Pull Down Current	V _{EN} = 5.5 V	I _{EN}		0.3	1	μΑ
Turn-On Time	From assertion of V _{EN} to V _{OUT} = 98% V _{OUT(NOM)} . V _{OUT(NOM)} = 1.2 V	t _{ON}		215		μs
Turn-On Slew Rate	V_{EN} 0 V to 1.0 V, $V_{OUT(NOM)}$ = 1.2 V, V_{OUT} from 10 mV to 610 mV	SR		15		mV/μs
Power Supply Rejection Ratio	V_{IN} to V_{OUT} , f = 1 kHz, I_{OUT} = 150 mA, $V_{IN} \ge V_{OUT}$ +0.5 V	PSRR(V _{IN})		70		dB
	V_{BIAS} to V_{OUT} , f = 1 kHz, I_{OUT} = 150 mA, $V_{IN} \ge V_{OUT}$ +0.5 V	PSRR(V _{BIAS})		80		dB
Output Noise Voltage	$V_{IN} = V_{OUT} + 0.5 \text{ V}, V_{OUT(NOM)} = 1.0 \text{ V},$ f = 10 Hz to 100 kHz	V _N		40		μV _{RMS}
Thermal Shutdown	Temperature increasing			160		°C
Threshold	Temperature decreasing			140		
Output Discharge Pull-Down	$V_{EN} \leq 0.4$ V, $V_{OUT} = 0.5$ V, NCP145A options only	R _{DISCH}		150		Ω

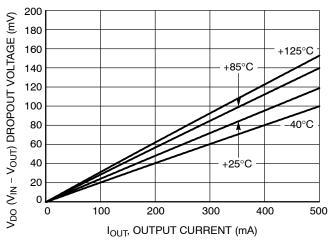
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{4.} Performance guaranteed over the indicated operating temperature range by design and/or characterization. Production tested at T_A = 25°C. Low duty cycle pulse techniques are used during the testing to maintain the junction temperature as close to ambient as possible.

^{5.} Dropout voltage is characterized when V_{OUT} falls 3% below V_{OUT}(NOM).

TYPICAL CHARACTERISTICS

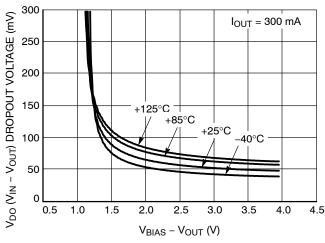
At T_J = +25°C, V_{IN} = $V_{OUT(TYP)}$ + 0.3 V, V_{BIAS} = 2.7 V, V_{EN} = V_{BIAS} , $V_{OUT(NOM)}$ = 1.0 V, I_{OUT} = 500 mA, C_{IN} = 1 μ F, C_{BIAS} = 0.1 μ F, and C_{OUT} = 2.2 μ F (effective capacitance), unless otherwise noted.



V_{DO} (V_{IN} - V_{OUT}) DROPOUT VOLTAGE (mV) 200 $I_{OUT} = 100 \text{ mA}$ 180 160 140 120 100 80 +125°C 60 +25°C -40°C 40 20 0.5 1.0 1.5 2.0 2.5 3.0 3.5 4.0 4.5 V_{BIAS} - V_{OUT} (V)

Figure 3. V_{IN} Dropout Voltage vs. I_{OUT} and Temperature T_J

Figure 4. V_{IN} Dropout Voltage vs. (V_{BIAS} – V_{OUT}) and Temperature T_J



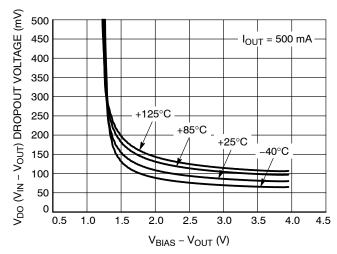
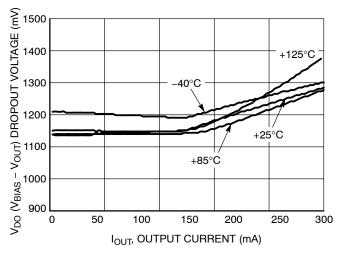


Figure 5. V_{IN} Dropout Voltage vs. (V_{BIAS} – V_{OUT}) and Temperature T_J

Figure 6. V_{IN} Dropout Voltage vs. (V_{BIAS} – V_{OUT}) and Temperature T_J



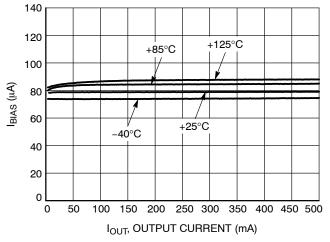
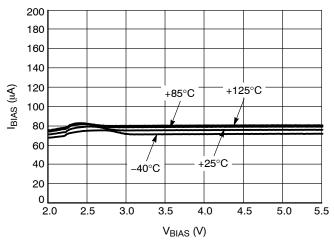


Figure 7. V_{BIAS} Dropout Voltage vs. I_{OUT} and Temperature T_J

Figure 8. BIAS Pin Current vs. I_{OUT} and Temperature T_J

TYPICAL CHARACTERISTICS

At T_J = +25°C, V_{IN} = V_{OUT(TYP)} + 0.3 V, V_{BIAS} = 2.7 V, V_{EN} = V_{BIAS}, V_{OUT(NOM)} = 1.0 V, I_{OUT} = 500 mA, C_{IN} = 1 μ F, C_{BIAS} = 0.1 μ F, and C_{OUT} = 2.2 μ F (effective capacitance), unless otherwise noted.



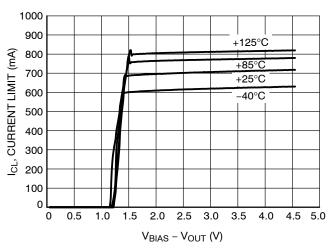


Figure 9. BIAS Pin Current vs. $V_{\mbox{\footnotesize BIAS}}$ and Temperature $T_{\mbox{\footnotesize J}}$

Figure 10. Current Limit vs. (V_{BIAS} - V_{OUT})

TYPICAL CHARACTERISTICS

At T_J = +25°C, V_{IN} = $V_{OUT(TYP)}$ + 0.3 V, V_{BIAS} = 2.7 V, V_{EN} = V_{BIAS} , $V_{OUT(NOM)}$ = 1.0 V, I_{OUT} = 500 mA, C_{IN} = 1 μ F, C_{BIAS} = 0.1 μ F, and C_{OUT} = 2.2 μ F (effective capacitance), unless otherwise noted.

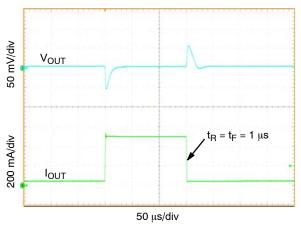


Figure 11. Load Transient Response, I_{OUT} = 50 mA to 500 mA, C_{OUT} = 10 μF

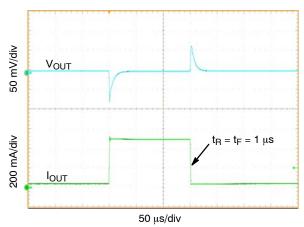


Figure 12. Load Transient Response, I_{OUT} = 50 mA to 500 mA, C_{OUT} = 2.2 μF

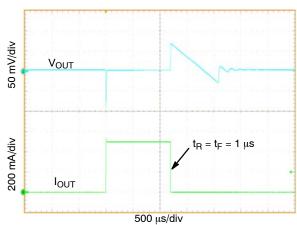


Figure 13. Load Transient Response, I_{OUT} = 1 mA to 500 mA, C_{OUT} = 10 μF

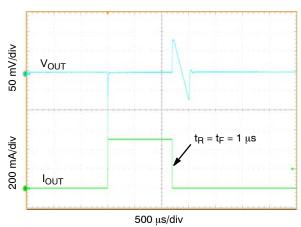


Figure 14. Load Transient Response, I_{OUT} = 1 mA to 500 mA, C_{OUT} = 2.2 μF

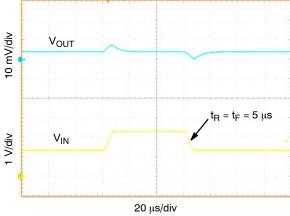


Figure 15. V_{IN} Line Transient Response, V_{IN} = 1.3 V to 2.3 V, I_{OUT} = 100 mA, C_{OUT} = 10 μF

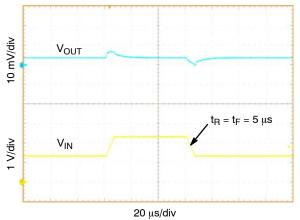


Figure 16. V_{IN} Line Transient Response, V_{IN} = 1.3 V to 2.3 V, I_{OUT} = 100 mA, C_{OUT} = 2.2 μF

APPLICATIONS INFORMATION

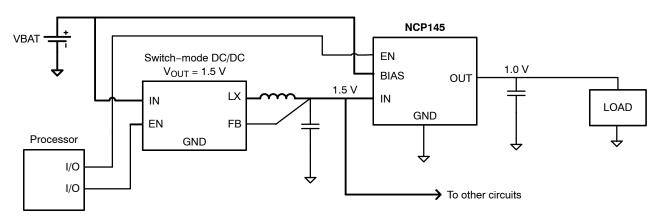


Figure 17. Typical Application: Low-Voltage DC/DC Post-Regulator with ON/OFF Functionality

The NCP145 dual–rail very low dropout voltage regulator is using NMOS pass transistor for output voltage regulation from $V_{\rm IN}$ voltage. All the low current internal control circuitry is powered from the $V_{\rm BIAS}$ voltage.

The use of an NMOS pass transistor offers several advantages in applications. Unlike PMOS topology devices, the output capacitor has reduced impact on loop stability. Vin to Vout operating voltage difference can be very low compared with standard PMOS regulators in very low Vin applications.

The NCP145 offers smooth monotonic start-up. The controlled voltage rising limits the inrush current.

The Enable (EN) input is equipped with internal hysteresis. NCP145 Voltage linear regulator Fixed version is available.

Dropout Voltage

Because of two power supply inputs V_{IN} and V_{BIAS} and one V_{OUT} regulator output, there are two Dropout voltages specified.

The first, the V_{IN} Dropout voltage is the voltage difference $(V_{IN}-V_{OUT})$ when V_{OUT} starts to decrease by percent specified in the Electrical Characteristics table. V_{BIAS} is high enough; specific value is published in the Electrical Characteristics table.

The second, V_{BIAS} dropout voltage is the voltage difference ($V_{BIAS} - V_{OUT}$) when V_{IN} and V_{BIAS} pins are joined together and V_{OUT} starts to decrease.

Input and Output Capacitors

The device is designed to be stable for ceramic output capacitors with Effective capacitance in the range from $2.2 \,\mu\text{F}$ to $10 \,\mu\text{F}$. The device is also stable with multiple capacitors in parallel, having the total effective capacitance in the specified range.

In applications where no low input supplies impedance available (PCB inductance in V_{IN} and/or V_{BIAS} inputs as example), the recommended C_{IN} = 1 μF and C_{BIAS} = 0.1 μF

or greater. Ceramic capacitors are recommended. For the best performance all the capacitors should be connected to the NCP145 respective pins directly in the device PCB copper layer, not through vias having not negligible impedance.

When using small ceramic capacitor, their capacitance is not constant but varies with applied DC biasing voltage, temperature and tolerance. The effective capacitance can be much lower than their nominal capacitance value, most importantly in negative temperatures and higher LDO output voltages. That is why the recommended Output capacitor capacitance value is specified as Effective value in the specific application conditions.

Enable Operation

The enable pin will turn the regulator on or off. The threshold limits are covered in the electrical characteristics table in this data sheet. If the enable function is not to be used then the pin should be connected to V_{IN} or V_{BIAS} .

Current Limitation

The internal Current Limitation circuitry allows the device to supply the full nominal current and surges but protects the device against Current Overload or Short.

Thermal Protection

Internal thermal shutdown (TSD) circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When TSD activated, the regulator output turns off. When cooling down under the low temperature threshold, device output is activated again. This TSD feature is provided to prevent failures from accidental overheating.

Activation of the thermal protection circuit indicates excessive power dissipation or inadequate heatsinking. For reliable operation, junction temperature should be limited to +125°C maximum.

ORDERING INFORMATION

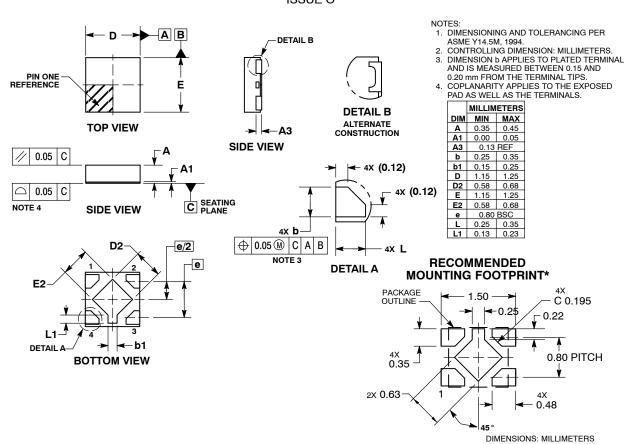
Device	Nominal Output Voltage	Marking	Option	Package	Shipping [†]
NCP145AMX100TCG	1.00 V	HE			
NCP145AMX105TCG	1.05 V	05 V HG	Output Active Discharge	XDFN4 (Pb-Free)	3000 / Tape & Reel
NCP145AMX120TCG	1.20 V	HD	Ŭ	,	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

To order other package and voltage variants, please contact your ON Semiconductor sales representative

PACKAGE DIMENSIONS

XDFN4 1.2x1.2, 0.8P CASE 711BC **ISSUE O**



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. Coverage may be accessed at www.onsemi.com/site/par/-atent_-warking.pgr. On Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT

0

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free

Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative